
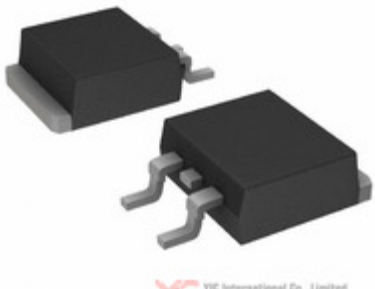








	<p>SUD40N08-16-E3</p>
	<p>Hersteller-Teilenummer: SUD40N08-16-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 80V 40A TO252</p> <p>Datenblätter:  SUD40N08-16-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 18202 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SUD40N08-16-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 80V 40A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	18202 pcs Stock
Hersteller Standard Vorlaufzeit	33 Weeks
detaillierte Beschreibung	N-Channel 80V 40A (Tc) 3W (Ta), 136W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	3W (Ta), 136W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	40A (Tc)
Rds On (Max) @ Id, Vgs	16 mOhm @ 40A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1960pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SUD40N08-16-E3DKR

SUD40N08-16-E3 ist neu im Original, Suche SUD40N08-16-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD40N08-16-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD40N08-16-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD40N10-25-E3 Vishay / Siliconix MOSFET N-CH 100V 40A TO252</p>	 <p>SUD40N08-16 VISHAY SUD40N08-16 VISHAY</p>	 <p>SUD40N08-16-E3. VB SUD40N08-16-E3. VB</p>	 <p>SUD40N06-25L-E3 VIS VIS TO-252</p>
 <p>SUD40N06L-25 VISHAY VISHAY TO-252</p>	 <p>SUD40N08-16_08 V SUD40N08-16_08 V</p>	 <p>SUD40N08-16-T4-E3 VISHAY SUD40N08-16-T4-E3 VISHAY</p>	 <p>SUD40N08-16-E3 Vishay / Siliconix MOSFET N-CH 80V 40A TO252</p>

heiße Teile

Mehr

⊛ SUD30N04-10	↔ SUD30N04-10-E3	⇒ SUD30N06-30	D SUD35N05-26L	↔ SUD35N05-26L-E3
⊣ SUD35N05-26L-E3	⊛ SUD35N10-26P	D SUD35N10-26P-E3	⇒ SUD35N10-26P-E3	↔ SUD35N10-26P-GE3
⊛ SUD35N10-26P-GE3	⊣ SUD40N02-08-E3	⊛ SUD40N02-08-E3	↔ SUD40N02-3M3P	↔ SUD40N02-3M3P-E3
D SUD40N02-3M3P-E3	⊛ SUD40N03-18P	⊣ SUD40N03-18P-E3	⊛ SUD40N04	↔ SUD40N04-10A
⇒ SUD40N04-10A-E3	↔ SUD40N04-10A-E3	⊛ SUD40N04-20	⊣ SUD40N06-25L	↔ SUD40N08-16
↔ SUD40N08-16-E3	⇒ SUD40N08-16-E3.	D SUD40N08-16-T4-E3	⊛ SUD40N08-16_08	⊣ SUD40N10-25
⊛ SUD40N10-25-E3	D SUD40N10-25-E3	⇒ SUD40P03-20	↔ SUD42N03-3M9P	↔ SUD42N03-3M9P-GE3
⊣ SUD42N03-3M9P-GE3	⊛ SUD45N03-09	↔ SUD45N05-20	⇒ SUD45N05-20L	↔ SUD45N05-20L-E3
⊛ SUD45P03-09	⊣ SUD45P03-09-E3	⊛ SUD45P03-09-GE3	D SUD45P03-09-GE3	↔ SUD45P03-10
↔ SUD45P03-10-E3	⊛ SUD45P03-10-E3	⊣ SUD45P03-15	⊛ SUD45P03-15-E3	↔ SUD45P03-15-E3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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